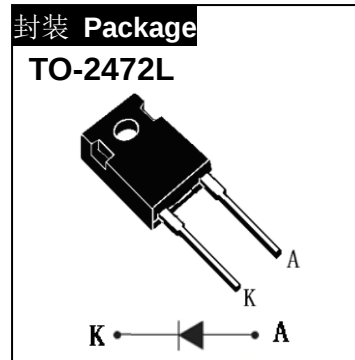




60F60WT

主要参数 MAIN CHARACTERISTICS

$I_F(AV)$	60A
V_{RRM}	600 V
$V_F(typ)$	1.6V
$T_{rr} (typ)$	40ns



用途

- 吸收回路
- 开关电源
- 高频开关器件并联二极管

APPLICATIONS

- Snubber diode
- Switch power supply
- Antiparalle Diode for high frequency switching devices

产品特性

- 超快恢复时间
- 低恢复损耗
- 低正向压降
- 低漏电流

FEATURES

- Ultrafast Recovery Time
- Low Recovery Loss
- Low Forward Voltage
- Low Leakage Current

订货信息 ORDER MESSAGE

订 货 型 号 Order codes		印 记 Marking	封 装 Package
有卤-条管 Halogen-Tube	无卤-条管 Halogen Free-Tube		
60F60WT-GL-B	60F60WT-GL-BR	60F60WT	TO-2472L



**绝对最大额定值 ABSOLUTE RATINGS** ($T_c=25^{\circ}\text{C}$)

项 目 Parameter	符 号 Symbol	数 值 Value	单 位 Unit
反向重复峰值电压 Peak Repetitive Reverse Voltage	V_{RRM}	600	V
平均正向整流电流 $T_c=135^{\circ}\text{C}$ Average Forward Rectified Current	$I_{F(AV)}$	60	A
非重复浪涌正向电流 Non-Repetitive Surge Forward Current $t=8.3\text{ms}$	I_{FSM}	480	A
雪崩能量 Avalanche Energy(per diode) ($L=40\text{mH}$)	E_{AVL}	20	mJ
结温 Junction Temperature	T_j	$-55\sim+175$	$^{\circ}\text{C}$
存储温度 Storage temperature range	T_{STG}	$-55\sim+175$	$^{\circ}\text{C}$

电特性 ELECTRICAL CHARACTERISTICS ($T_c=25^{\circ}\text{C}$ unless otherwise specified)

项 目 Parameter	测试条件 Tests conditions		最小值 Value(min)	典型值 Value(typ)	最大值 Value(max)	单位 Unit
V _R	I _R =50μA		600	-	-	V
I _R	T _j =25℃	V _R =V _{RRM}	-	-	10	μA
	T _j =125℃		-	-	800	μA
V _F	T _j =25℃	I _F =60A	-	1.6	2.3	V
	T _j =125℃		-	-	2.0	V
trr	I _F =0.5A, I _R =1A, I _{RR} =0.25A		-	45	55	ns
trr	I _F =1A, V _R =30V, di _F /dt=-100A/μs		-	-	45	ns
trr	I _F =60A, V _R =200V, di _F /dt=-200A/μs T _C =25℃		-	27	-	ns
Q _{rr}			-	33	-	nc
I _{RRM}			-	1.5	-	A
trr	I _F =60A, V _R =200V, di _F /dt=-200A/μs T _C =125℃		-	91	-	ns
Q _{rr}			-	173	-	nc
I _{RRM}			-	3.8	-	A

热特性 THERMAL CHARACTERISTICS (maximum)

项 目 Parameter	符 号 Symbol	最大值 Value(max)	单 位 Unit
结到管壳的热阻 Thermal Resistance Junction to Case	$R_{th(j-c)}$	0.34	$^{\circ}\text{C}/\text{W}$





特征曲线 ELECTRICAL CHARACTERISTICS (curves)

Fig.1 TYPICAL FORWARD CHARACTERISTICS

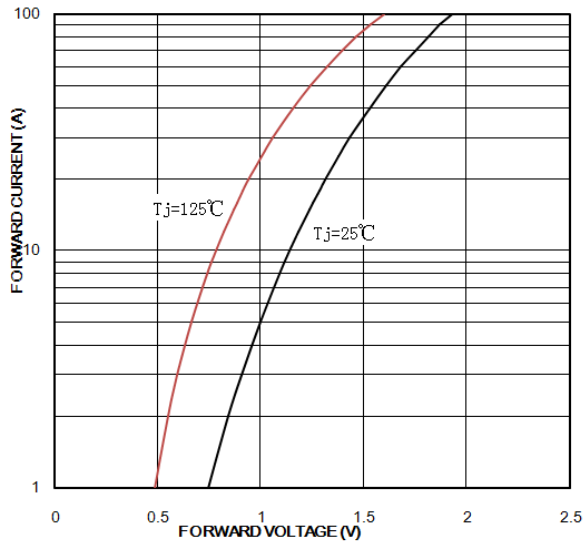


Fig.2 TYPICAL REVERSE CHARACTERISTICS

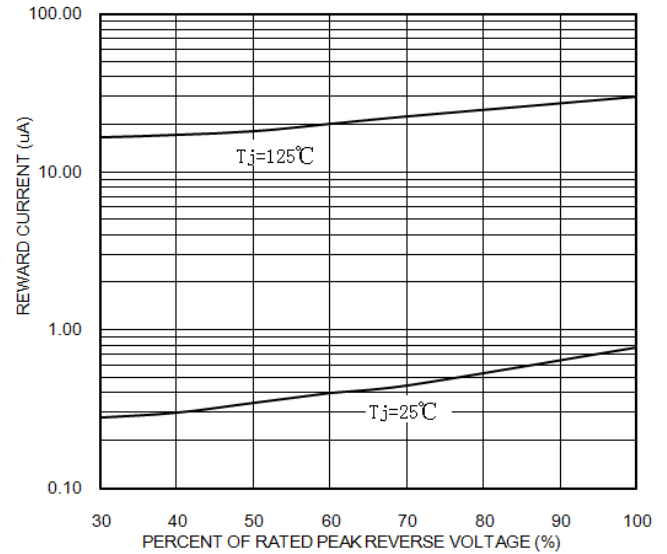


Fig.3 TYPICAL JUNCTION CAPACITANCE

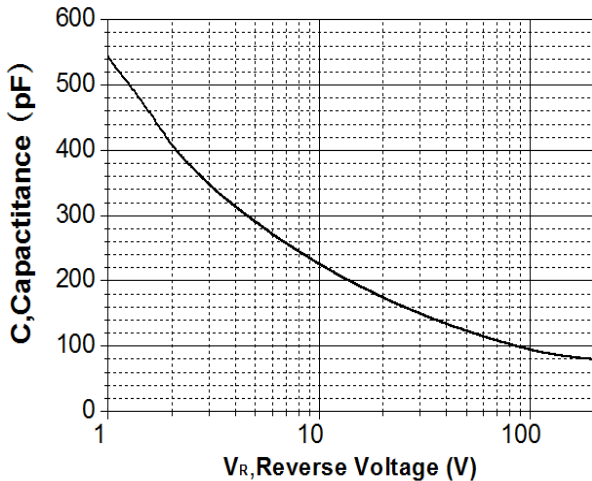


Fig.4 Reverse recovery time versus di/dt

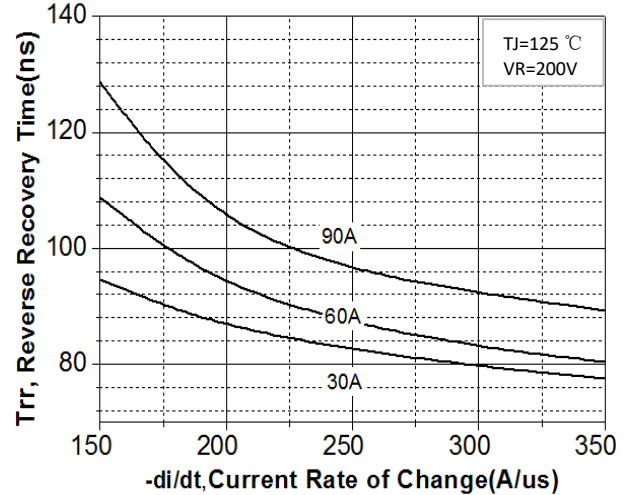


Fig.5 Reverse recovery charges versus di/dt

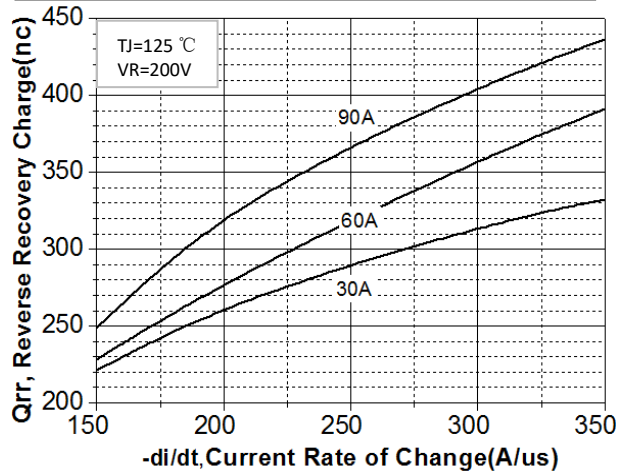


Fig.6 Peak reverse recovery current versus di/dt

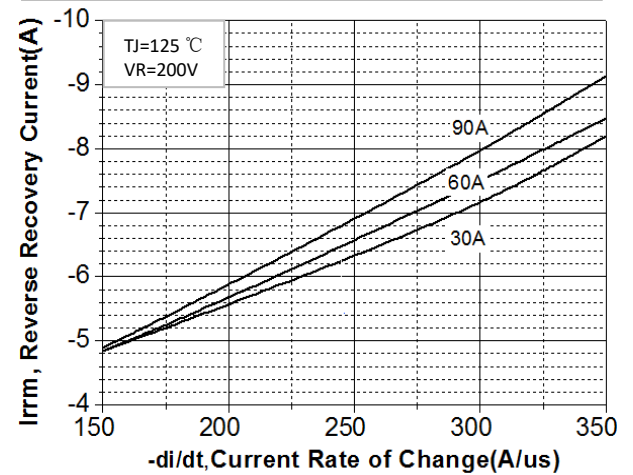


Fig.7 FORWARD CURRENT DERATING CURVE

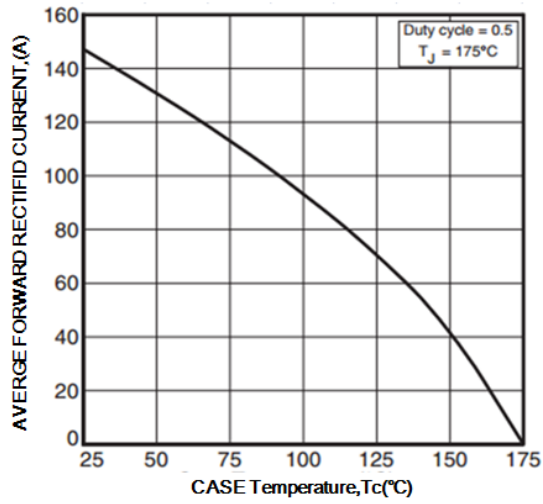
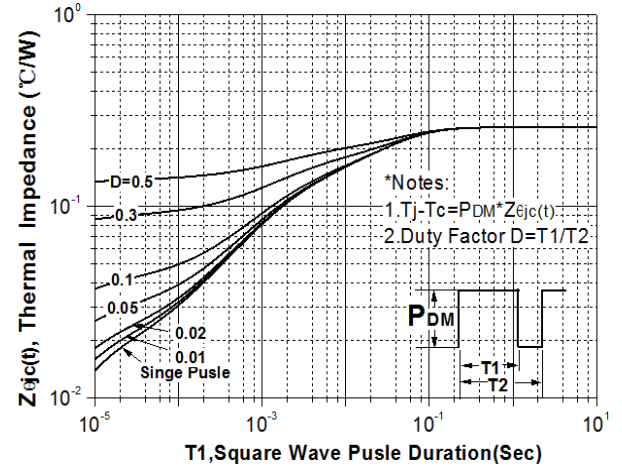


Fig.8 Transient Thermal Response Curve

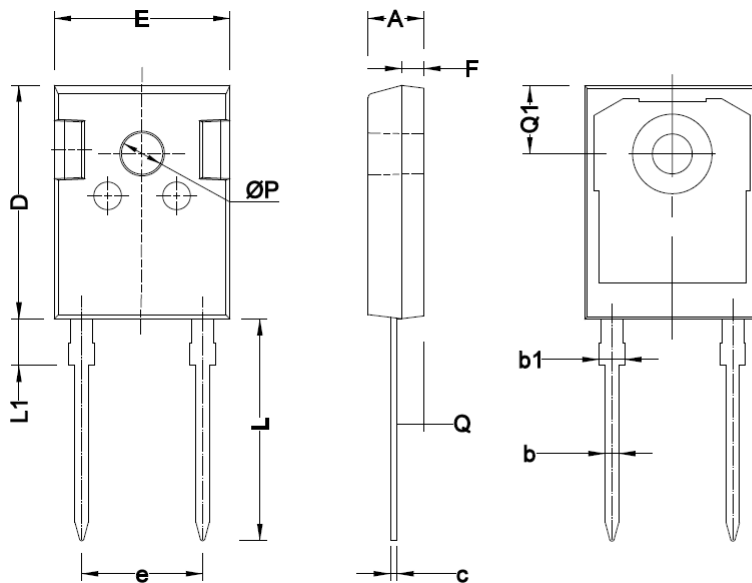




外形尺寸 PACKAGE MECHANICAL DATA

TO-247 2L

单位 Unit : mm

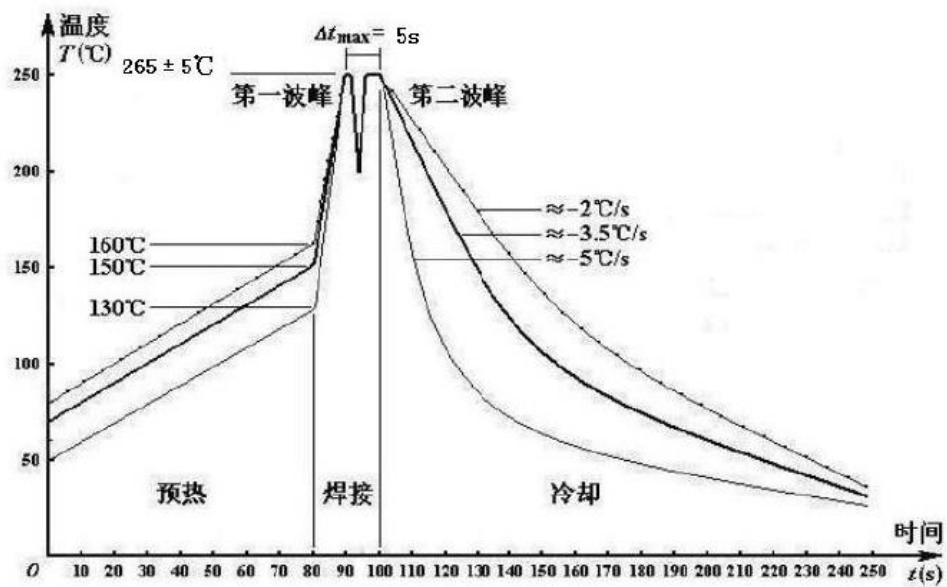


SYMBOL	MM	
	MIN	MAX
A	4.80	5.20
b	1.10	1.30
b1	1.95	2.25
c	0.50	0.70
D	20.80	21.20
E	15.60	16.00
F	1.85	2.15
e	10.73	11.03
L	19.62	20.22
L1	3.93	4.33
ØP	3.40	3.80
Q	2.26	2.56
Q1	6.00	6.40

焊接方式：波峰焊

焊接工艺曲线

wave soldering





注意事项

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3. 在电路设计时请不要超过器件的绝对最大额定值，否则会影响整机的可靠性。
4. 本说明书如有版本变更不另外告知。

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3. Please do not exceed the absolute maximum ratings of the device when circuit designing.
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联系方式

吉林华微电子股份有限公司

公司地址：吉林省吉林市深圳街 99 号

邮编：132013

总机：86-432-64678411

传真：86-432-64665812

网址：www.hwdz.com.cn

CONTACT

JILIN SINO-MICROELECTRONICS CO., LTD.

ADD: No.99 Shenzhen Street, Jilin City, Jilin Province, China.

Post Code: 132013

Tel: 86-432-64678411

Fax: 86-432-64665812

Web Site: www.hwdz.com.cn